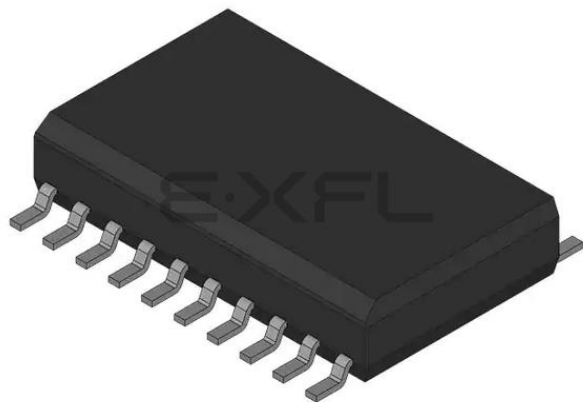




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Details

Product Status	Active
Core Processor	HC08
Core Size	8-Bit
Speed	8MHz
Connectivity	-
Peripherals	LED, LVD, POR, PWM
Number of I/O	15
Program Memory Size	4KB (4K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	A/D 12x8b
Oscillator Type	External
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SOIC (0.295", 7.50mm Width)
Supplier Device Package	20-SOIC
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mc908jk3emdwe

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Central Processor Unit (CPU)

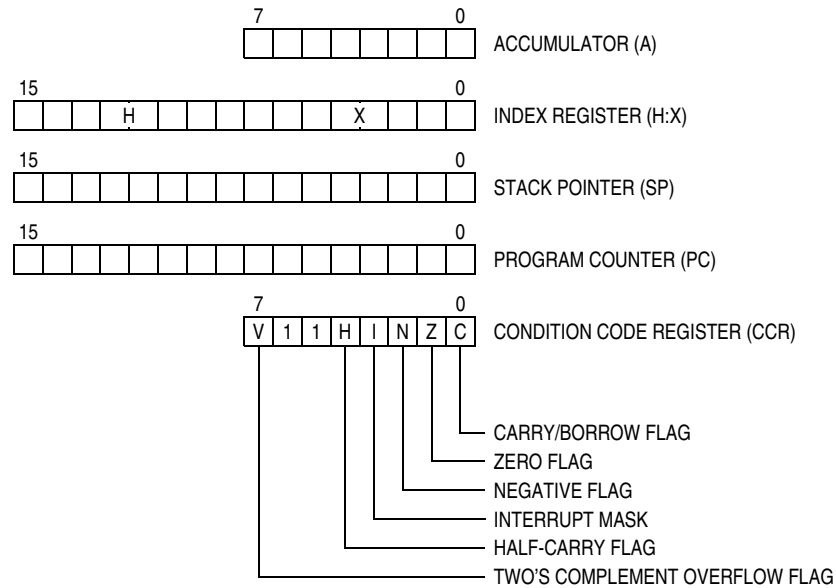


Figure 4-1. CPU Registers

4.3.1 Accumulator

The accumulator is a general-purpose 8-bit register. The CPU uses the accumulator to hold operands and the results of arithmetic/logic operations.

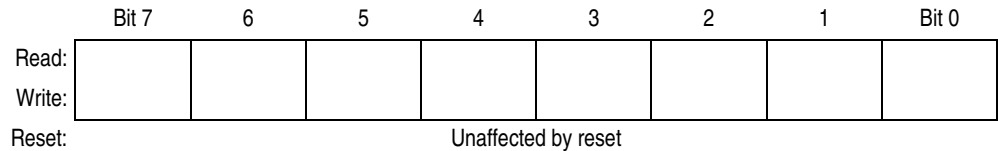


Figure 4-2. Accumulator (A)

4.3.2 Index Register

The 16-bit index register allows indexed addressing of a 64-Kbyte memory space. H is the upper byte of the index register, and X is the lower byte. H:X is the concatenated 16-bit index register.

In the indexed addressing modes, the CPU uses the contents of the index register to determine the conditional address of the operand.

The index register can serve also as a temporary data storage location.

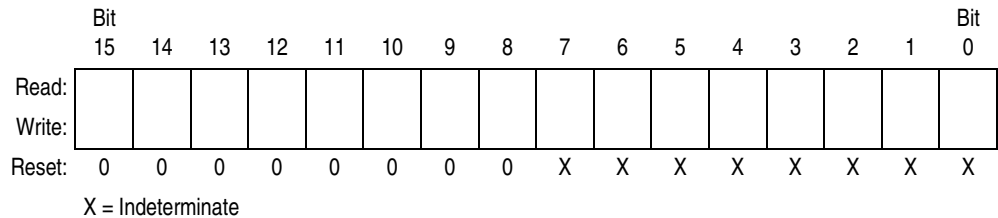


Figure 4-3. Index Register (H:X)

4.3.3 Stack Pointer

The stack pointer is a 16-bit register that contains the address of the next location on the stack. During a reset, the stack pointer is preset to \$00FF. The reset stack pointer (RSP) instruction sets the least significant byte to \$FF and does not affect the most significant byte. The stack pointer decrements as data is pushed onto the stack and increments as data is pulled from the stack.

In the stack pointer 8-bit offset and 16-bit offset addressing modes, the stack pointer can function as an index register to access data on the stack. The CPU uses the contents of the stack pointer to determine the conditional address of the operand.

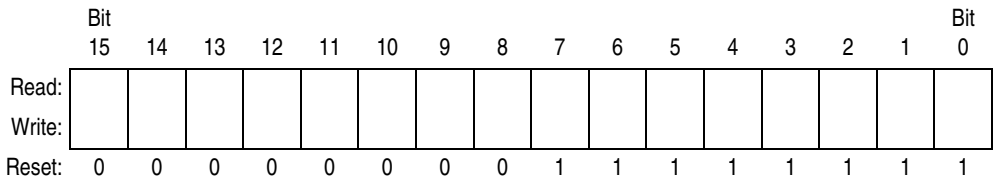


Figure 4-4. Stack Pointer (SP)

NOTE

The location of the stack is arbitrary and may be relocated anywhere in random-access memory (RAM). Moving the SP out of page 0 (\$0000 to \$00FF) frees direct address (page 0) space. For correct operation, the stack pointer must point only to RAM locations.

4.3.4 Program Counter

The program counter is a 16-bit register that contains the address of the next instruction or operand to be fetched.

Normally, the program counter automatically increments to the next sequential memory location every time an instruction or operand is fetched. Jump, branch, and interrupt operations load the program counter with an address other than that of the next sequential location.

During reset, the program counter is loaded with the reset vector address located at \$FFFE and \$FFFF. The vector address is the address of the first instruction to be executed after exiting the reset state.

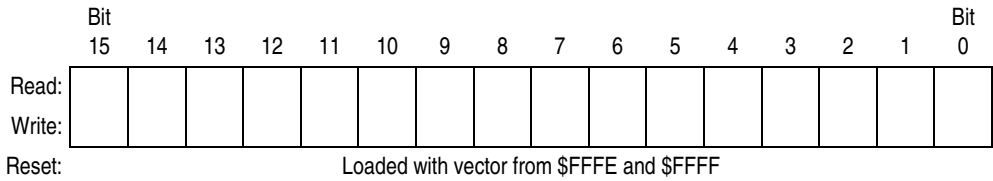


Figure 4-5. Program Counter (PC)

Table 4-1. Instruction Set Summary (Sheet 5 of 6)

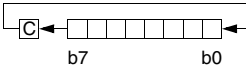
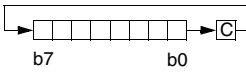
Source Form	Operation	Description	Effect on CCR					Address Mode	Opcode	Operand	Cycles
			V	H	I	N	Z				
PULA	Pull A from Stack	$SP \leftarrow (SP + 1); \text{Pull (A)}$	–	–	–	–	–	INH	86		2
PULH	Pull H from Stack	$SP \leftarrow (SP + 1); \text{Pull (H)}$	–	–	–	–	–	INH	8A		2
PULX	Pull X from Stack	$SP \leftarrow (SP + 1); \text{Pull (X)}$	–	–	–	–	–	INH	88		2
ROL <i>opr</i> ROLA ROLX ROL <i>opr</i> ,X ROL ,X ROL <i>opr</i> ,SP	Rotate Left through Carry		↑	–	–	–	↑	DIR INH INH IX1 IX SP1	39 49 59 69 79 9E69	dd ff ff	4 1 1 4 3 5
ROR <i>opr</i> RORA RORX ROR <i>opr</i> ,X ROR ,X ROR <i>opr</i> ,SP	Rotate Right through Carry		↑	–	–	–	↑	DIR INH INH IX1 IX SP1	36 46 56 66 76 9E66	dd ff ff	4 1 1 4 3 5
RSP	Reset Stack Pointer	$SP \leftarrow \$FF$	–	–	–	–	–	INH	9C		1
RTI	Return from Interrupt	$SP \leftarrow (SP + 1); \text{Pull (CCR)}$ $SP \leftarrow (SP + 1); \text{Pull (A)}$ $SP \leftarrow (SP + 1); \text{Pull (X)}$ $SP \leftarrow (SP + 1); \text{Pull (PCH)}$ $SP \leftarrow (SP + 1); \text{Pull (PCL)}$	↑	↑	↑	↑	↑	INH	80		7
RTS	Return from Subroutine	$SP \leftarrow SP + 1; \text{Pull (PCH)}$ $SP \leftarrow SP + 1; \text{Pull (PCL)}$	–	–	–	–	–	INH	81		4
SBC # <i>opr</i> SBC <i>opr</i> SBC <i>opr</i> SBC <i>opr</i> ,X SBC <i>opr</i> ,X SBC ,X SBC <i>opr</i> ,SP SBC <i>opr</i> ,SP	Subtract with Carry	$A \leftarrow (A) - (M) - (C)$	↑	–	–	–	↑	IMM DIR EXT IX2 IX1 IX SP1 SP2	A2 B2 C2 D2 E2 F2 9EE2 9ED2	ii dd hh ll ee ff ff ff ff ff ee ff	2 3 4 4 3 2 4 5
SEC	Set Carry Bit	$C \leftarrow 1$	–	–	–	–	1	INH	99		1
SEI	Set Interrupt Mask	$I \leftarrow 1$	–	–	1	–	–	INH	9B		2
STA <i>opr</i> STA <i>opr</i> STA <i>opr</i> ,X STA <i>opr</i> ,X STA ,X STA <i>opr</i> ,SP STA <i>opr</i> ,SP	Store A in M	$M \leftarrow (A)$	0	–	–	↑	↑	DIR EXT IX2 IX1 IX SP1 SP2	B7 C7 D7 E7 F7 9EE7 9ED7	dd hh ll ee ff ff ff ff ff ee ff	3 4 4 3 2 4 5
STHX <i>opr</i>	Store H:X in M	$(M:M + 1) \leftarrow (H:X)$	0	–	–	↑	↑	DIR	35	dd	4
STOP	Enable Interrupts, Stop Processing, Refer to MCU Documentation	$I \leftarrow 0$; Stop Processing	–	–	0	–	–	INH	8E		1
STX <i>opr</i> STX <i>opr</i> STX <i>opr</i> ,X STX <i>opr</i> ,X STX ,X STX <i>opr</i> ,SP STX <i>opr</i> ,SP	Store X in M	$M \leftarrow (X)$	0	–	–	↑	↑	DIR EXT IX2 IX1 IX SP1 SP2	BF CF DF EF FF 9EEF 9EDF	dd hh ll ee ff ff ff ff ff ee ff	3 4 4 3 2 4 5
SUB # <i>opr</i> SUB <i>opr</i> SUB <i>opr</i> SUB <i>opr</i> ,X SUB <i>opr</i> ,X SUB ,X SUB <i>opr</i> ,SP SUB <i>opr</i> ,SP	Subtract	$A \leftarrow (A) - (M)$	↑	–	–	–	↑	IMM DIR EXT IX2 IX1 IX SP1 SP2	A0 B0 C0 D0 E0 F0 9EE0 9ED0	ii dd hh ll ee ff ff ff ff ee ff	2 3 4 4 3 2 4 5

Table 7-8. READSP (Read Stack Pointer) Command

Description	Reads stack pointer
Operand	None
Data Returned	Returns stack pointer in high byte:low byte order
Opcode	\$0C
Command Sequence	

Table 7-9. RUN (Run User Program) Command

Description	Executes RTI instruction
Operand	None
Data Returned	None
Opcode	\$28
Command Sequence	

7.4 Security

A security feature discourages unauthorized reading of Flash locations while in monitor mode. The host can bypass the security feature at monitor mode entry by sending eight security bytes that match the bytes at locations \$FFF6–\$FFFD. Locations \$FFF6–\$FFFD contain user-defined data.

NOTE

Do not leave locations \$FFF6–\$FFFD blank. For security reasons, program locations \$FFF6–\$FFFD even if they are not used for vectors.

During monitor mode entry, the MCU waits after the power-on reset for the host to send the eight security bytes on pin PTB0. If the received bytes match those at locations \$FFF6–\$FFFD, the host bypasses the security feature and can read all Flash locations and execute code from Flash. Security remains bypassed until a power-on reset occurs. If the reset was not a power-on reset, security remains bypassed and security code entry is not required. (See Figure 7-7.)

TOVx — Toggle-On-Overflow Bit

When channel x is an output compare channel, this read/write bit controls the behavior of the channel x output when the TIM counter overflows. When channel x is an input capture channel, TOVx has no effect. Reset clears the TOVx bit.

1 = Channel x pin toggles on TIM counter overflow.

0 = Channel x pin does not toggle on TIM counter overflow.

NOTE

When TOVx is set, a TIM counter overflow takes precedence over a channel x output compare if both occur at the same time.

CHxMAX — Channel x Maximum Duty Cycle Bit

When the TOVx bit is at one, setting the CHxMAX bit forces the duty cycle of buffered and unbuffered PWM signals to 100%. As Figure 8-8 shows, the CHxMAX bit takes effect in the cycle after it is set or cleared. The output stays at the 100% duty cycle level until the cycle after CHxMAX is cleared.

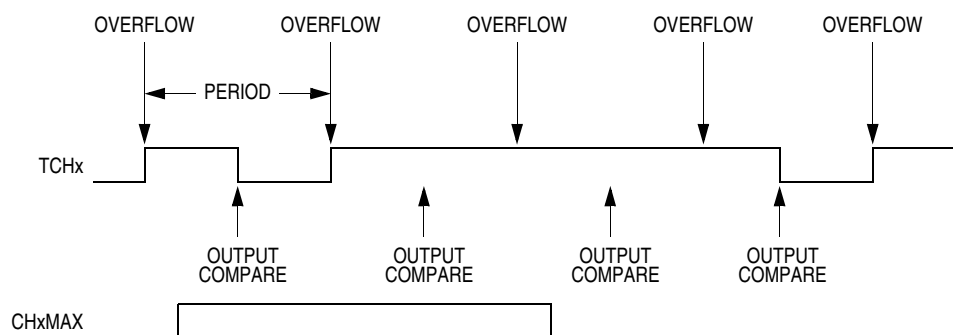


Figure 8-8. CHxMAX Latency

8.9.5 TIM Channel Registers (TCH0H/L:TCH1H/L)

These read/write registers contain the captured TIM counter value of the input capture function or the output compare value of the output compare function. The state of the TIM channel registers after reset is unknown.

In input capture mode ($MSxB:MSxA = 0:0$), reading the high byte of the TIM channel x registers (TCHxH) inhibits input captures until the low byte (TCHxL) is read.

In output compare mode ($MSxB:MSxA \neq 0:0$), writing to the high byte of the TIM channel x registers (TCHxH) inhibits output compares until the low byte (TCHxL) is written.

Address:	\$0026	TCH0H						
	Bit 7	6	5	4	3	2	1	Bit 0
Read:								
Write:	Bit15	Bit14	Bit13	Bit12	Bit11	Bit10	Bit9	Bit8
Reset:	Indeterminate after reset							
Address:	\$0027	TCH0L						
	Bit 7	6	5	4	3	2	1	Bit 0
Read:								
Write:	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
Reset:	Indeterminate after reset							
Address:	\$0029	TCH1H						
	Bit 7	6	5	4	3	2	1	Bit 0
Read:								
Write:	Bit15	Bit14	Bit13	Bit12	Bit11	Bit10	Bit9	Bit8
Reset:	Indeterminate after reset							
Address:	\$02A	TCH1L						
	Bit 7	6	5	4	3	2	1	Bit 0
Read:								
Write:	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
Reset:	Indeterminate after reset							

Figure 8-9. TIM Channel Registers (TCH0H/L:TCH1H/L)

10.2 Port A

Port A is an 7-bit special function port that shares all seven of its pins with the keyboard interrupt (KBI) module (see Chapter 12 Keyboard Interrupt Module (KBI)). Each port A pin also has software configurable pull-up device if the corresponding port pin is configured as input port. PTA0 to PTA5 has direct LED drive capability.

NOTE

*PTA0–PTA5 pins are available on MC68H(R)C908JL3E only.
PTA6 pin is available on MC68HRC908JL3E/JK3E/JK1E only.*

10.2.1 Port A Data Register (PTA)

The port A data register (PTA) contains a data latch for each of the seven port A pins.

Address: \$0000

	Bit 7	6	5	4	3	2	1	Bit 0
Read:	0	PTA6	PTA5	PTA4	PTA3	PTA2	PTA1	PTA0
Write:								
Reset:	Unaffected by Reset							
Additional Functions:			LED (Sink)	LED (Sink)	LED (Sink)	LED (Sink)	LED (Sink)	LED (Sink)
		30k pull-up	30k pull-up	30k pull-up	30k pull-up	30k pull-up	30k pull-up	30k pull-up
		Keyboard Interrupt	Keyboard Interrupt	Keyboard Interrupt	Keyboard Interrupt	Keyboard Interrupt	Keyboard Interrupt	Keyboard Interrupt

= Unimplemented

 = Unimplemented

Figure 10-2. Port A Data Register (PTA)

PTA[6:0] — Port A Data Bits

These read/write bits are software programmable. Data direction of each port A pin is under the control of the corresponding bit in data direction register A. Reset has no effect on port A data.

KBI[6:0] — Port A Keyboard Interrupts

The keyboard interrupt enable bits, KBIE[6:0], in the keyboard interrupt control register (KBIER) enable the port A pins as external interrupt pins, (see Chapter 12 Keyboard Interrupt Module (KBI)).

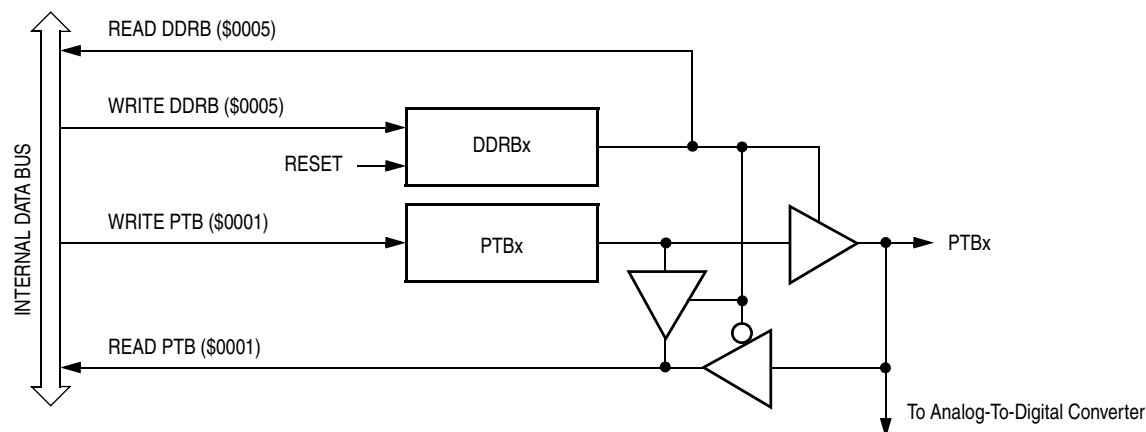


Figure 10-8. Port B I/O Circuit

When DDRBx is a 1, reading address \$0001 reads the PTBx data latch. When DDRBx is a 0, reading address \$0001 reads the voltage level on the pin. The data latch can always be written, regardless of the state of its data direction bit. Table 10-3 summarizes the operation of the port B pins.

Table 10-3. Port B Pin Functions

DDRB Bit	PTB Bit	I/O Pin Mode	Accesses to DDRB	Accesses to PTB	
			Read/Write	Read	Write
0	X ⁽¹⁾	Input, Hi-Z ⁽²⁾	DDRB[7:0]	Pin	PTB[7:0] ⁽³⁾
1	X	Output	DDRB[7:0]	Pin	PTB[7:0]

1. X = don't care.
2. Hi-Z = high impedance.
3. Writing affects data register, but does not affect the input.

12.5.2 Keyboard Interrupt Enable Register

The port-A keyboard interrupt enable register enables or disables each port-A pin to operate as a keyboard interrupt pin.

Address:	\$001B							
	Bit 7	6	5	4	3	2	1	Bit 0
Read:	0	KBIE6	KBIE5	KBIE4	KBIE3	KBIE2	KBIE1	KBIE0
Write:								
Reset:	0	0	0	0	0	0	0	0

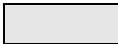
 = Unimplemented

Figure 12-4. Keyboard Interrupt Enable Register (KBIER)

KBIE6–KBIE0 — Port-A Keyboard Interrupt Enable Bits

Each of these read/write bits enables the corresponding keyboard interrupt pin on port-A to latch interrupt requests. Reset clears the keyboard interrupt enable register.

1 = KBIx pin enabled as keyboard interrupt pin

0 = KBIx pin not enabled as keyboard interrupt pin

12.6 Low-Power Modes

The WAIT and STOP instructions put the MCU in low power-consumption standby modes.

12.6.1 Wait Mode

The keyboard modules remain active in wait mode. Clearing the IMASKK bit in the keyboard status and control register enables keyboard interrupt requests to bring the MCU out of wait mode.

12.6.2 Stop Mode

The keyboard module remains active in stop mode. Clearing the IMASKK bit in the keyboard status and control register enables keyboard interrupt requests to bring the MCU out of stop mode.

12.7 Keyboard Module During Break Interrupts

The system integration module (SIM) controls whether the keyboard interrupt latch can be cleared during the break state. The BCFE bit in the break flag control register (BFCR) enables software to clear status bits during the break state.

To allow software to clear the keyboard interrupt latch during a break interrupt, write a 1 to the BCFE bit. If a latch is cleared during the break state, it remains cleared when the MCU exits the break state.

To protect the latch during the break state, write a 0 to the BCFE bit. With BCFE at 0 (its default state), writing to the keyboard acknowledge bit (ACKK) in the keyboard status and control register during the break state has no effect.

13.3.7 COPRS (COP Rate Select)

The COPRS signal reflects the state of the COP rate select bit (COPRS) in the configuration register 1.

Address:	\$001F							
	Bit 7	6	5	4	3	2	1	Bit 0
Read:	COPRS	R	R	LVID	R	SSREC	STOP	COPD
Write:								
Reset:	0	0	0	0	0	0	0	0
	R = Reserved							

Figure 13-2. Configuration Register 1 (CONFIG1)

COPRS — COP Rate Select Bit

COPRS selects the COP timeout period. Reset clears COPRS.

1 = COP timeout period is $8176 \times 20SCOUT$ cycles

0 = COP timeout period is $262,128 \times 20SCOUT$ cycles

COPD — COP Disable Bit

COPD disables the COP module.

1 = COP module disabled

0 = COP module enabled

13.4 COP Control Register

The COP control register is located at address \$FFFF and overlaps the reset vector. Writing any value to \$FFFF clears the COP counter and starts a new timeout period. Reading location \$FFFF returns the low byte of the reset vector.

Address:	\$FFFF							
	Bit 7	6	5	4	3	2	1	Bit 0
Read:	Low byte of reset vector							
Write:	Clear COP counter							
Reset:	Unaffected by reset							

Figure 13-3. COP Control Register (COPCTL)

13.5 Interrupts

The COP does not generate CPU interrupt requests.

13.6 Monitor Mode

The COP is disabled in monitor mode when V_{TST} is present on the $\overline{IRQ}$ pin or on the $\overline{RST}$ pin.

13.7 Low-Power Modes

The WAIT and STOP instructions put the MCU in low-power consumption standby modes.



Break Module (BREAK)

16.3 Functional Operating Range

Table 16-2. Operating Range

Characteristic	Symbol	Value		Unit
Operating temperature range	T_A	–40 to +125	–40 to +85	°C
Operating voltage range	V_{DD}	$5 \pm 10\%$	$3 \pm 10\%$	V

16.4 Thermal Characteristics

Table 16-3. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal resistance	θ_{JA}		
20-pin PDIP		70	°C/W
20-pin SOIC		70	°C/W
28-pin PDIP		70	°C/W
28-pin SOIC		70	°C/W
48-pin LQFP		80	°C/W
I/O pin power dissipation	$P_{I/O}$	User determined	W
Power dissipation ⁽¹⁾	P_D	$P_D = (I_{DD} \times V_{DD}) + P_{I/O} =$ $K/(T_J + 273 \text{ °C})$	W
Constant ⁽²⁾	K	$P_D \times (T_A + 273 \text{ °C})$ $+ P_D^2 \times \theta_{JA}$	W/°C
Average junction temperature	T_J	$T_A + (P_D \times \theta_{JA})$	°C

1. Power dissipation is a function of temperature.

2. K constant unique to the device. K can be determined for a known T_A and measured P_D . With this value of K, P_D and T_J can be determined for any value of T_A .

16.10 3V Oscillator Characteristics

Table 16-9. Oscillator Component Specifications (3V)

Characteristic	Symbol	Min	Typ	Max	Unit
Crystal frequency, XTALCLK	f_{OSCCLK}	—	8	16	MHz
RC oscillator frequency, RCCLK	f_{RCCLK}	2	8	12	MHz
External clock reference frequency ⁽¹⁾	f_{OSCCLK}	dc	—	16	MHz
Crystal load capacitance ⁽²⁾	C_L	—	—	—	
Crystal fixed capacitance ⁽²⁾	C_1	—	$2 \times C_L$	—	
Crystal tuning capacitance ⁽²⁾	C_2	—	$2 \times C_L$	—	
Feedback bias resistor	R_B	—	10 M Ω	—	
Series resistor ^{(2), (3)}	R_S	—	—	—	
RC oscillator external R	R_{EXT}	See Figure 16-2			
RC oscillator external C	C_{EXT}	—	10	—	pF

1. No more than 10% duty cycle deviation from 50%.
2. Consult crystal vendor data sheet.
3. Not required for high frequency crystals.

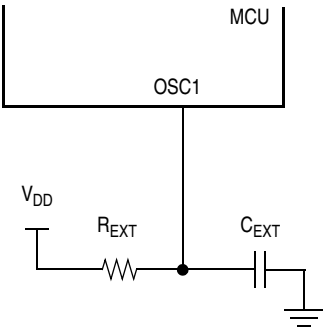
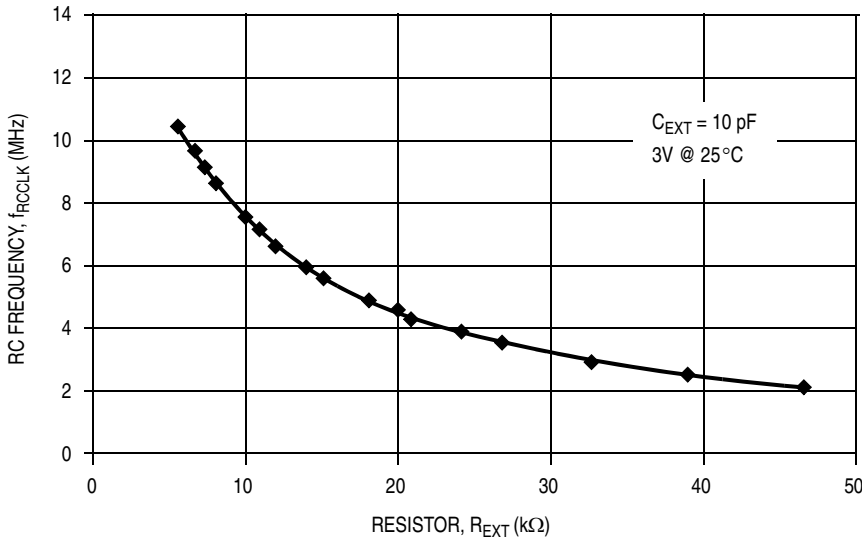
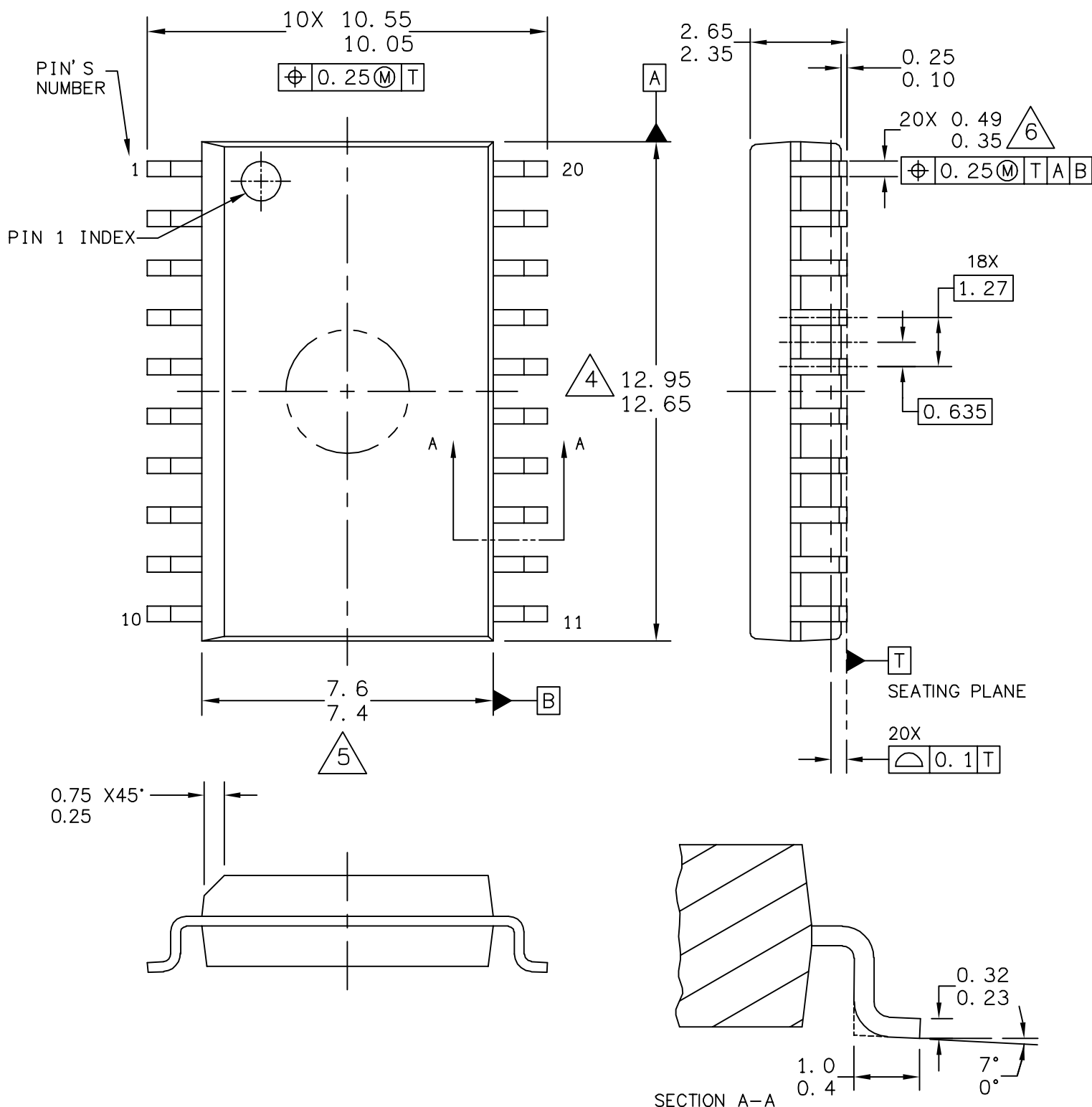


Figure 16-2. RC vs. Frequency (3V @25°C)



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TITLE: 20LD SOIC W/B, 1.27 PITCH CASE-OUTLINE	DOCUMENT NO: 98ASB42343B		REV: J	
	CASE NUMBER: 751D-07		23 MAR 2005	
	STANDARD: JEDEC MS-013AC			

A.5.5 ADC Characteristics

Table A-5. ADC Characteristics

Characteristic	Symbol	Min	Max	Unit	Comments
Supply voltage	V_{DDAD}	2.2 (V_{DD} min)	5.5 (V_{DD} max)	V	
Input voltages	V_{ADIN}	V_{SS}	V_{DD}	V	
Resolution	B_{AD}	8	8	Bits	
Absolute accuracy	A_{AD}	± 0.5	± 2	LSB	Includes quantization
ADC internal clock	f_{ADIC}	0.5	1.048	MHz	$t_{AIC} = 1/f_{ADIC}$, tested only at 1 MHz
Conversion range	R_{AD}	V_{SS}	V_{DD}	V	
Power-up time	t_{ADPU}	14	—	t_{AIC} cycles	
Conversion time	t_{ADC}	14	15	t_{AIC} cycles	
Sample time ⁽¹⁾	t_{ADS}	5	—	t_{AIC} cycles	
Zero input reading ⁽²⁾	Z_{ADI}	00	01	Hex	$V_{IN} = V_{SS}$
Full-scale reading ⁽³⁾	F_{ADI}	FE	FF	Hex	$V_{IN} = V_{DD}$
Input capacitance	C_{ADI}	—	(20) 8	pF	Not tested
Input leakage ⁽³⁾ Port B/port D	—	—	± 1	μA	

1. Source impedances greater than 10 k Ω adversely affect internal RC charging time during input sampling.
2. Zero-input/full-scale reading requires sufficient decoupling measures for accurate conversions.
3. The external system error caused by input leakage current is approximately equal to the product of R source and input current.

A.5.6 Memory Characteristics

The Flash memory can only be read at an operating voltage of 2.2 to 5.5V. Program and erase are achieved at an operating voltage of 2.7 to 5.5V. The program and erase parameters in Table A-6 are for $V_{DD} = 2.7$ to 5.5V only.

Table A-6. Memory Characteristics

Characteristic	Symbol	Min	Max	Unit
RAM data retention voltage	V_{RDR}	1.3	—	V
Flash program bus clock frequency	—	1	—	MHz
Flash read bus clock frequency	$f_{Read}^{(1)}$	32k	8M	Hz
Flash page erase time	$t_{Erase}^{(2)}$	1	—	ms
Flash mass erase time	$t_{MErase}^{(3)}$	4	—	ms
Flash PGM/ERASE to HVEN set up time	t_{nvs}	10	—	μ s
Flash high-voltage hold time	t_{nvh}	5	—	μ s
Flash high-voltage hold time (mass erase)	t_{nvhl}	100	—	μ s
Flash program hold time	t_{pgs}	5	—	μ s
Flash program time	t_{PROG}	30	40	μ s
Flash return to read time	$t_{rcv}^{(4)}$	1	—	μ s
Flash cumulative program hv period	$t_{HV}^{(5)}$	—	4	ms
Flash row erase endurance ⁽⁶⁾	—	10k	—	cycles
Flash row program endurance ⁽⁷⁾	—	10k	—	cycles
Flash data retention time ⁽⁸⁾	—	10	—	years

1. f_{Read} is defined as the frequency range for which the Flash memory can be read.

2. If the page erase time is longer than t_{Erase} (Min), there is no erase-disturb, but it reduces the endurance of the Flash memory.

3. If the mass erase time is longer than t_{MErase} (Min), there is no erase-disturb, but it reduces the endurance of the Flash memory.

4. t_{rcv} is defined as the time it needs before the Flash can be read after turning off the high voltage charge pump, by clearing HVEN to 0.

5. t_{HV} is defined as the cumulative high voltage programming time to the same row before next erase.

t_{HV} must satisfy this condition: $t_{nvs} + t_{nvh} + t_{pgs} + (t_{PROG} \times 32) \leq t_{HV} \text{ max.}$

6. The minimum row endurance value specifies each row of the Flash memory is guaranteed to work for at least this many erase / program cycles.

7. The minimum row endurance value specifies each row of the Flash memory is guaranteed to work for at least this many erase / program cycles.

8. The Flash is guaranteed to retain data over the entire operating temperature range for at least the minimum time specified.

B.7 Electrical Specifications

Electrical specifications for the MC68H(R)C908JL3E/JK3E apply to the MC68H(R)C08JL3E/JK3E, except for the parameters indicated below.

B.7.1 DC Electrical Characteristics

Table B-2. DC Electrical Characteristics (5V)

Characteristic ⁽¹⁾	Symbol	Min	Typ ⁽²⁾	Max	Unit
V _{DD} supply current, f _{OP} = 4 MHz					
Run ⁽³⁾					
MC68HC08JL3E/JK3E		—	9	11	mA
MC68HRC08JL3E/JK3E		—	4.3	5	mA
Wait ⁽⁴⁾					
MC68HC08JL3E/JK3E		—	5.5	6.5	mA
MC68HRC08JL3E/JK3E		—	0.8	1.5	mA
Stop ⁽⁵⁾	I _{DD}				
(–40°C to 85°C)					
MC68HC08JL3E/JK3E		—	1.8	5	μA
MC68HRC08JL3E/JK3E		—	1.8	5	μA
(–40°C to 125°C)					
MC68HC08JL3E/JK3E		—	5	10	μA
MC68HRC08JL3E/JK3E		—	5	10	μA
Pullup resistors ⁽⁶⁾					
PTD6, PTD7	R _{PU1}	1.8	4.3	4.8	kΩ
RST, IRQ, PTA0–PTA6	R _{PU2}	16	31	36	kΩ

1. V_{DD} = 4.5 to 5.5 Vdc, V_{SS} = 0 Vdc, T_A = T_L to T_H, unless otherwise noted.

2. Typical values reflect average measurements at midpoint of voltage range, 25 °C only.

3. Run (operating) I_{DD} measured using external square wave clock source (f_{OP} = 4 MHz). All inputs 0.2V from rail. No dc loads. Less than 100 pF on all outputs. C_L = 20 pF on OSC2. All ports configured as inputs. OSC2 capacitance linearly affects run I_{DD}. Measured with all modules enabled.

4. Wait I_{DD} measured using external square wave clock source (f_{OP} = 4 MHz). All inputs 0.2V from rail. No dc loads. Less than 100 pF on all outputs. C_L = 20 pF on OSC2. All ports configured as inputs. OSC2 capacitance linearly affects wait I_{DD}.

5. Stop I_{DD} measured with OSC1 grounded; no port pins sourcing current. LVI is disabled.

6. R_{PU1} and R_{PU2} are measured at V_{DD} = 5.0V.

